Electronic transport of bilayer manganite La$_{1.2}$Sr$_{1.8}$Mn$_2$O$_7$

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Abstract

We report magnetoresistivity measurements on a La$_{1.2}$Sr$_{1.8}$Mn$_2$O$_7$ single crystal. The charge transport in the ferromagnetic phase is dominated by two-magnon scattering in the high $T$ range and by weak localization effects at lower $T$, in the non-metallic regime. In the paramagnetic phase, $\rho_s(T)$ obeys the adiabatic small polaron hopping mechanism, while $\rho_s(T)$ follows an Arrhenius behavior with the same activation energy.

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There is growing interest in the electrical transport phenomena of perovskite manganites in order to elucidate the microscopic origin of the colossal magnetoresistance (CMR) effect. The bilayer manganite La$_{2-x}$Sr$_{x}$Mn$_2$O$_7$ has proven to be a fruitful system for understanding the CMR [1]. Its reduced dimensionality gives rise to anisotropic characteristics of charge transport and magnetic properties and also enhances the CMR effect near the magnetic transition temperature. At present, the electronic transport mechanism of manganites remains controversial and is far from being fully understood. In this paper, we address this issue through resistivity measurements on a La$_{1.2}$Sr$_{1.8}$Mn$_2$O$_7$ single crystal.

Fig. 1(a) is a plot of $\sigma_{ab}$ and $\sigma_c$ of La$_{1.2}$Sr$_{1.8}$Mn$_2$O$_7$ for temperatures $T \leq 50$ K, down to 1.9 K, measured in zero field. Both $\sigma_{ab}$ and $\sigma_c$ follow a $T^{1/2}$ dependence below a certain $T$. It has been suggested [2] that the observed $T^{1/2}$ dependence of $\sigma_{ab}$ is consistent with weak localization effects in ordered three-dimensional (3D) metals. Since the crystal structure and the conductivity are strongly anisotropic, the bilayer manganites appear to be more 2D like. However, $\sigma_c(T)$ clearly follows the same $T^{1/2}$ dependence at low temperatures, consistent with 3D weak localization effects in disordered metals.

This $T^{1/2}$ behavior in both $\sigma_{ab}(T)$ and $\sigma_c(T)$ confirms the 3D nature of the metallic state and is in good agreement with the theory of quantum interference in highly anisotropic layer metals [3].

Fig. 1(b) shows the temperature $T$ dependence of the zero-field $\rho_{ab}$ and $\rho_c$ for $50 \leq T \leq 110$ K. In this $T$ regime, the experimental data follow a $T^{9/2}$ dependence of the form $\rho(T) = \rho_0 + BT^{9/2}$ (see the solid curves in Fig. 1(b)). This clearly reveals the two-magnon scattering nature [4] of the low-temperature resistivity in the ferromagnetic phase. The fitting coefficients $B$ for $\rho_{ab}$ and $\rho_c$ are $4.04 \times 10^{-13}$ and $2.83 \times 10^{-11}$ $\Omega$ cm/k$^{9/2}$, respectively. In La$_{1.2}$Sr$_{1.8}$Mn$_2$O$_7$, the hole concentration $n \equiv x = 0.40$, the in-plane hopping distance is $R_{ab} = 3.87$ Å [5], the magnitude of the effective spin is $S = 1.8$, the effective stiffness constant $D^*_{ab} = 151$ meV Å$^2$ based on recent neutron scattering measurements [6], and the effective hopping integral $t^*_{ab} = 40$ meV as estimated from the measured effective plasma frequency [7]. With these values, we obtained $B_{ab} = 1.01 \times 10^{-13}$ $\Omega$ cm/k$^{9/2}$ by using the expression of $B$ in the case of a simple parabolic band [7]. The calculated $B_{ab}$ has the same order of magnitude as the fitting parameter.

Based on the relationship $D = JSR^2$ with $J$ the strength of the magnetic exchange coupling, one obtains the ratio of $J_{ab}$ and $J_c$ as: $J_{ab}/J_c = (B_a R_c/B_c R_a)^3$ in terms of the analytical expression of $B$ [7]. With the fitted values of $B_{ab}$ and $B_c$, $R_{ab} = 3.87$ Å, and the out-of-plane hopping distance as the Mn–Mn distance between...
We observed that there is the following relationship between resistivities: \( \rho_c/\rho_{ab} = -14.8 + 2.63 \times 10^4/T \) for \( 150 \leq T \leq 400 \) K in zero field. It has been generally accepted that the resistivity in high-\( T \) paramagnetic phase follows the adiabatic small polaron transport mechanism with the form \( \rho = CT \exp(E_A/k_B T) \) [9]. To examine the polaronic nature of the high-\( T \) resistivity of La\(_{1.2}\)Sr\(_{1.8}\)Mn\(_2\)O\(_7\), we plot in Fig. 1(c), \( \ln(\rho_{ab,c}/T) \) vs. \( 1000/T \) for \( T \geq 140 \) K and in zero field. The adiabatic polaron model describes well the in-plane resistivity data for \( T \geq 218 \) K, with a zero-field activation energy \( E_A = 93.8 \) meV and a prefactor \( C = 2.0 \times 10^{-6} \) \( \Omega \) cm/K. In fact the out-of-plane resistivity can also be fitted using the adiabatic small polaron model. Considering the resistive anisotropy \( \rho_c/\rho_{ab} \), we can also describe \( \rho_c \), in an Arrhenius-type form with the same activation energy \( E_A \) as \( \rho_{ab} \), if the preexponential factor is taken into account.

In the adiabatic limit, the electron motion is assumed to be much faster than the ionic motion of the lattice. In the approximation that all correlations except on-site Coulomb repulsion are ignored, one can express the prefactor \( C \) as [10]: \( C = k_B \Omega/(\pi(1-x)^2 R^2 v) \), where \( \Omega \) is the unit-cell volume, \( x \) is the fraction concentration of occupied sites, and \( v \) is the frequency of the longitudinal optical phonons. Using the lattice parameters \( a = 3.87 \times 10^{-8} \) cm and \( c = 2.0 \times 10^{-7} \) cm [5], the doping level \( x = 0.4 \), and the characteristic frequency \( v = 2.42 \times 10^{14} \) Hz, taken from optical conductivity spectra [11], we obtained the adiabatic prefactor \( C = 1.85 \times 10^{-6} \) \( \Omega \) cm/K for La\(_{1.2}\)Sr\(_{1.8}\)Mn\(_2\)O\(_7\). The good agreement between the calculated value of \( C \) and the above fitting parameter of \( \rho_{ab} \) provides strong evidence in favor of small polaronic transport in the \( ab \) plane in the high-\( T \) paramagnetic state of bilayer manganites.

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**References**